Fabrication of Ti₃SiC₂ by Mechanical Alloying Under Air Atmosphere

Indra Sidharta, Sutikno, Wahyu Wijanarko

Laboratory of Metallurgy Department of Mechanical Engineering Institut Teknologi Sepuluh Nopember Kampus ITS Keputih Sukolilo, Surabaya 60111 sidarta@me.its.ac.id

Abstract

Ti₃SiC₂ is a member of the MAX phase material, which is a group of ternary compounds with the family formula of $M_{N+1}AX_N$. Ti₃SiC₂ has excellent properties such as machinability, low density, good damage tolerance, and high thermal stability due to the layered nature of its structure. Ti_3SiC_2 can be produced by many methods such as hot isostatic pressing (HIP), powder metallurgy, hot pressing, spark plasma sintering and mechanical alloying (MA). The result of s ynthesis of T i_3SiC_2 by m echanical alloying was comparable to other process, even though additional phases, such as TiC, TiSi₂, or Ti₅Si₃ may still be present in the final products. The objective of the experiment is to produce Ti_3SiC_2 using mechanical alloying under air atm osphere. Ti_3SiC_2 was produced by mechanical alloying using high energy ball milling machine under air at mosphere. Elemental powders of T i, Si, and C were used as raw materials for T i₃SiC₂ fabrication. Various powder compositions based on molar ratio, ball to powder ratio (BPR), milling speed and milling time were introduced to the process. X-ray diffraction (XRD) and scanning electron m icroscope (SEM) is used t o characterize as-milled powder. Afterwards, sintering was carried out to the selected powders in order to enhance the purity of the ternary carbide. The as-sintered products were also examined using XRD and SEM. Results showed that the amount of Ti_3SiC_2 in the as-milled powders was low. TiC was the major phases detected along with titanium silicides. Some of XRD pattern of as-milled powder exhibited amorphous pattern. The amount of Ti_3SiC_2 is increasing after sintering process. The formation of Ti_3SiC_2 involved mechanically induced self-propagating r eaction (MSR). However, due to contamination during milling the amount of the ternary carbide was low. The amount of Ti₃SiC₂ was enhanced after sintering, indicating that crystallization and nucleation of ternary carbides occurred during the process.

Keywords: mechanical alloying, air atmosphere, elemental powders, mechanically induced self-propagating reaction (MSR), contamination.

Pendahuluan

 Ti_3SiC_2 is a member of the MAX phase material, which is a group of ternary compounds with the family formula: $M_{N+1}AX_N$; where N is an integer 1, 2 or 3; M is a transition metal; A is an element from groups IIB to VIA in the periodic table of the elements; and X is either carbon or nitro gen. Structure of M_{N+1}AX_N phase material is lay ered hexagonal with two form ula units per unit cell. Ti₃SiC₂ consists of la yered structure with planar Si layer linked together by Ti₆C octahedral. The layered nature of T i₃SiC₂ can re adily be obs erved on its fracture surface (Li, J.F., 1999). Ti₃SiC₂ exhibits a combination of exceptional properties of both metal and ceramic. The layered nature of Ti₃SiC₂ influences the exceptional properties (Barsoum, 2001).

Excellent machinability, low density, good damage tolerance, high t hermal stability, high oxidation

resistance, good electrical and therm al conductivity, and high t hermal shock resistance are am ong the promising properties (Barsoum, 2001). It is worth to note that particular properties, such as machinability, give this material a credit. The fact t hat it is ver y readily machinable using conventional tool an d evidence of self lubricating is a great technolo gical importance (Barsoum, 2001, 1996). Many synthesis methods have been developed in order to produce high purity Ti₃SiC₂, namely sintering, hot isostatic pressing (HIP), hot pressing (HP), combustion synthesis or self propagating hi gh temperature synthesis (SHS), pulse discha rge sintering and spark plasma sintering (SPS) (Li, J.F ... 1999, Li, H., 20 04, Yeh, 2008, Zhou, 2005, Zhu, 2003). Apart from using elemental powder, the synthesis can also be done using combination of elemental powder with TiC, SiC, or Al₄C₃ as starting material. All the mentioned methods are performed at high temperature and most of them require extensive soaking time. Recently, many efforts have been done to produce using mechanic al alloying and the results were comparable to t hose using other synthesis methods (Jin, 200 7, Li, S.-B.Zhai, 2005, Liang, B.Y.M.Z.Wang, 2009). It is considerably better than the methods mentioned previously in term of en ergy and time consumption.

Most of the works on synthesis of T i_3SiC_2 by mechanical alloying used elemental powders as starting materials, and the results were comparable to other process, even though additional phases, such as TiC, TiSi₂, Ti₅Si₃ or Al₃Ti may still be present in the final products. Various reaction mechanisms for formation of Ti_3SiC_2 by MA have been proposed, however most of the m involved mechanically induced self-propagating reaction (MSR) (Jin, 2007, Li, S.-B.Zhai, 2005). MSR is self sustaining reaction induced by ball milling, and has relation wi th self-propagating high-temperature synthesis (SHS) reaction (Takacs, 2002). Concisely, MSR is а of ball combination milling induced, mechanochemical or mechanical alloying with combustive, explosive, self-propagating reacti on (SHS). The objective of the experiment is to produce Ti₃SiC₂ using mechanical alloying under air atmosphere.

Experimental Methods

 Ti_3SiC_2 was produced by mechanical alloying using high energy ball milling machine under air atmosphere. Elemental powders were used in the milling, and weighed according to molar ratio based on the following stoichiometric reactions:

$$3Ti + Si + 2C \rightarrow Ti_3SiC_2$$
 (1)

Table 1. Parameters used in the milling process

Specimen	Composition (molar ratio)	BPR*	Milling Speed (RPM)	Milling Time (hour)
TSC-1	3Ti/1Si/2C	20:1	300	1.5
TSC-2	3Ti/1Si/2C	20:1	300	3
TSC-3	3Ti/1Si/2C	20:1	500	1.5
TSC-4	3Ti/1Si/2C	20:1	500	3
TSC-5	3Ti/1Si/2C/0.1Al	10:1	300	6
TSC-6	3Ti/1Si/2C/0.1Al	10:1	300	8
TSC-7	3Ti/1Si/2C/0.1Al	10:1	300	10

Ti (99.9% purity, $<45\,\mu$ m), Si (99% purity, $<44\,\mu$ m), and C (99% purity, $<45\,\mu$ m) powders were used as raw materials for Ti₃SiC₂ fabrication. Small addition of Al powder (99% purity, $<75\,\mu$ m) was used to enhance the form ation of T i₃SiC₂ (Jin, 2007). Parameters that were used in the m illing of Ti3SiC2 are shown in table 1. Stainless steel jar was used as a grinding jar. Chromium steel (AISI 52100) balls with diameter of 10 mm and 15 mm were used as grinding balls.

X-ray diffraction (XRD) was us ed to charact erize as-milled powder. Afterwards, sintering was carrie d out to the selected powders in order t o enhance the purity of the ternary carbide. The powders were cold pressed to for m compacts with dia meter of 30 mm and a height of about 5 mm, and then pressureless sintered in a vacuum furnace at $1000 \degree C$ for 1 hour. Afterwards, the sintered specimens were investigated by mean of XRD. The fr acture surface of sintered specimens was exa mined using scanning electron microscope (SEM).



Figure 1. XRD patterns of as-milled Ti₃SiC₂ specimens



Figure 2. ARD patterns of as-sintered 113SIC₂ spec

Results and Discussion

Figure 1 shows the XRD patterns of as-m illed Ti3SiC2. It can be se en that specimen TSC-1 exhibited only elemental phases Ti and Si. Carbon peaks could not be o bserved in all of the XRD patterns because of the form ation of am orphous carbon or distribution of C in the grain boun daries of Ti or Si. Low intensity peaks of Ti_3SiC_2 could be seen in specimen TSC-2, indicating its sm all amount. TiC was the main phase in specimen TSC-2, as indicated by its high intensity. Two forms of titanium silicides, Ti_5Si_3 and $TiSi_2$, could also be observed in the

specimen. In the XRD pa tterns of specimen TSC-3 and TSC-4, only TiC and Ti peaks were appeared. Both TiC and Ti peaks were broad and the intensit y was very low , indicating the presence of nanocrystalline or amorphous phases.

Specimen TSC-5 to TSC-7 was added by Al powders. Ti_3SiC_2 peaks appeared i n the XRD patterns of all three specimens however, the intensity was still lower. The low intensity indicated that the am ount of Ti3SiC2 was small. TiC was still the main phase, and titanium silicides rem ained detectable in the entire specimen. By comparing the result of these three specimens to specimen TSC-2, it could be seen tha t there was low or no incre ase in the peaks of Ti_3SiC_2 . A decrease in the intensity of $TiSi_2$ peaks due to the addition of Al was observable in specimen to specimen TSC-7.

Figure 2 represents the XRD patterns of specime $n Ti_3SiC_2$ after being sintered at 10 00°C for 1 hour in vacuum condition. Specimen TSC-1 was not si ntered due to the presence of elemental phases Ti and Si. It

can be seen that there was a considerable increase in the intensity and number of peaks of T i₃SiC₂ phase compared to as-milled specimens. Having the highest intensity, TiC was still the m ain phase in all specimens. Some peaks of TiSi₂ remained in the sintered specimens. Sintered specimen TSC-7 displayed an increase of the intensity of $TiSi_2$ in 2 θ range of 38.5°-39.5°. Ti₅Si₃ phase was also detected in sintered specimens; however, the intensity was low, indicating the amount being small. Addition of Al in pecimen TSC-7 created specimen TSC-5 to s significant effect on phase formation of Ti₃SiC₂ and suppressing the formation of titanium silicides. The figure reveals that the intensity of $T_{i3}SiC_2$ peaks in specimen TSC-5 to TSC-7 are h igher than in specimen TSC-2 to TSC-4. More peaks of T i₃SiC₂ could also be found in specimen with Al additi on. Suppression of TiSi₂ and promotion of Ti₃SiC₂ could be observed clearly in 2θ degree of $38^{\circ}-40^{\circ}$ i n specimen TSC-5 and TSC-6. Both of the m were milled with same milling parameter, except that specimen TSC-6 had Al addition. In specimen without Al (TSC-2 to TSC-4), the intensity of TiSi₂ was higher than the intensity of Ti₃SiC₂. The opposite condition occurs in speci men with Al addition (TSC-5 to TSC-7) where the intensity of Ti_3SiC_2 was higher than that of TiSi₂.

The fracture surface of a sintered specimen (specimen TSC-7) is shown in Figure 3. It can be seen that the sintering did not produce fully dense morphology. Most of the powder is still in individual particle and having particle size of less than $1 \,\mu\text{m}$. Hence, the intensity of Ti₃SiC₂ did not increase significantly after sintering.



Figure 3. SEM micrograph of the fracture surface of as-sintered Ti_3SiC_2

Results of as-milled Ti_3SiC_2 specimen suggested that the amount of corresponding phases i.e. Ti_3SiC_2 were low. XRD patterns of as-milled T i_3SiC_2 exhibit low intensity of Ti_3SiC_2 peaks accompanied by high intensity of TiC peaks and som e small peaks of the titanium silicides, i.e. Ti_5S_3 and $TiSi_2$. Some of the Ti_3SiC_2 specimens exhibit am orphous-like XRD pattern with TiC as dominant phase. The presence of both TiC and titanium silicides, i.e. $TiSi_2$ and Ti_5Si_3 are unavoidable since the form ation of T i3SiC2 involves those phases.

The formation of Ti_3SiC_2 during milling may occur according to the following reactions as proposed by Li and Zhai (Li, S.-B.Zhai, 2005), and Jin et al (Jin, 2007):

$Ti + C \rightarrow TiC$	(1)	
$Ti + 2Si \rightarrow TiSi_2$	(2)	
$5Ti + 3Si \rightarrow Ti_5Si_3$	(3)	
TiC + Ti-Si liquid → T	i ₃ SiC ₂	(4)

During the milling, T i, Si and C powder under go repeated impact, which leads to the refinement of their particle size. When the powders achieve a critical particle size, Ti and C react first and form TiC. The formation of T iC involves the mechanis m so called mechanically induced self-propagation reaction (MSR), as suggested by numbers of work (Jin, 2007, Li, S.-B.ZhaiZhou, 2005, Jia, 2009). The formation of TiC releases a large amount of heat that leads to the formation of titanium silicides and Ti_3SiC_2 . The heat release d during the formation of TiC is high enough to induce the melting of Ti-Si system (Li, S.-B.Zhai, 2005). Then, T iC reacts with Ti-Si liquid to form Ti₃SiC₂. The addition of Al into Ti-Si-C system promotes the formation of Ti_3SiC_2 by affecting the reactions mentioned previously (reaction 1-3) as proposed by Jin et al (Jin, 2007). Jin proposed that Alm ight react with TiC, TiSi₂, and T i₅Si₃, inducing the formation of Ti₃SiC₂.

Figure 4 shows the fracture surface of specimen TSC-7 in another location. It can be seen that there is

a localized melting region as indicated by the arrow. EDX examination, depicted in Figure 5 revealed the the melted-like region is Ti_3SiC_2 . Therefore, it is clear that the for mation of T i_3SiC_2 in this experiment is also governed by the MSR. The EDX exam ination also revealed the presence of oxy gen, even though the quantity was low.

Though the formation of Ti_3SiC_2 this work is based on MSR, t he amount of corresponding phases obtained in the as-milled specimen is surprisingly low. The specimens of Ti_3SiC_2 which was added by Al powders which were fabricated based on particular references (Jin, 2007, Liang, B.Y.M.Z.Wang, 2009) yielded different result than the result of reference s. Those specimens yielded lower purit y of corresponding phases than the results of references. The condition was not ch anging even after sintering process.

Final Ti₃SiC₂ specimen displays a purity that is similar to the result of the work of Li et al (Li, S.-B.ZhaiZhou, 2005) and Liang et al (Liang, B.Han, 2009). However, it should be noted that the results of the final speci mens was obtained after sintering, while in t he references m entioned earlier was obtained from as-milled specimens in powder f orm. The bulk form of the refe rences shows better purity than the result of final sp ecimens. It is obvi ous that the results obtained in this work are i nfluenced by few mechanisms. It is likely that the air at mosphere that was used in the fab rication is responsible for such results. The possible mechanisms related to the event are discussed in the following paragraphs. Particle size is decreasing in a faster r ate when the milling is perform ed under air atmosphere (Saji, 1994). As stated in the second chapter , the MSR occurs when the milled powder reaches a particular critical size. Therefore, it is poss ible that the condition for the MSR i n this work, i.e. critical particle size, is achieved faster than in the reference works. The phases obt ained by the MSR are decreased in size with further milling time, yielding



Figure 4. SEM micrograph of the fracture surface of as-sintered Ti_3SiC_2 in di fferent location. Arrow indicates a melted-like region.

the amorphous-like XRD pattern. Thus, some of the specimens exhibit amorphous-like XRD pattern.

Milling under air at mosphere may introduce contamination into the system (Suryanarayana, 2004). Saji et al (Sa ji, 1994) found that the content of O,N, and C is increased as the increase of milling time if air was used as milling atmosphere. The MSR may occur in the powder during the milling; however, the number of MSR and the heat released may be lower than in the reference works (Jin, 200 7, Liang, B.Y.M.Z.Wang, 2009) due to the presence of contamination.

It is also possible that when oxide particularly amorphous oxide existed during the milling, it will cover other particles. H ence, when the MSR ignites, only particles or parts that are not cove red by oxide can undergo the process. Then, further milling time refines the particle size. Other evidence that supports the mechanism described above is that, there is no bulk products obtained i n as-milled specimens as obtained in several works (Liang, B.Han, 2009).

The condition above suit s the conditi on of Ti_3SiC_2 specimen that was m illed based on reference works. TiC may dominate the result even though the MSR in the system is limited. The form ation of T iC is not only achievable by MSR, but also by gradual reaction through elemental diffusion (Jia, 2009).

After sintering, all results show an improvement. The intensity of all corresp onding peaks is enhanced significantly. The enhancement may be resulted from the mechanisms described in the following. The first possible mechanism is that the sintering enhances the nucleation process of corresponding phases i.e. Ti_3SiC_2 mechanical alloyed powder mixture in the solid state (Li, J.-F., 2002). Mechanical alloy ing makes the powder very active because of their lar ge surface areas and m echanically induced strain. Therefore, the corresponding phase can be obtained by sintering at relatively lower temperature.



The second possible mechanism invol ves an assumption that the corresponding phases have already existed in the as- milled powder, but it is in nanocrystalline or am orphous state. During sintering

the amorphous phase under goes crystallization (Pei, 2005). The crystal growth also happens in the nanocrystalline phase. Hence, the in tensity of all phases i.e. Ti_3SiC_2 and T iC is enhanced after sintering.

XRD pattern of sinte red specimen exhibite d improvement in the amount of Ti_3SiC_2 . However, the dominant phase is still T iC. Therefore, it is m ost likely that the formation mechanism of Ti_3SiC_2 in this work occurred in the following manner:

- First, the MSR occurs during m illing and forms Ti_3SiC_2 , titanium silicides and TiC. However, since the MSR is li mited due to the contamination during m illing, the result is not satisfactory. Further milling time decreases the particle size, reaching the nanocry stalline or amorphous state.
- Second, the sintering enhances the intensity of the phases by inducing crystallization on amorphous phases, while the nanocry stalline phases undergo crystal growth. Nucleation of Ti₃SiC₂ may also occur during the sintering, leading to the increase of the amount of Ti₃SiC₂.

Ti₃SiC₂ is succes sfully prepared by mechanical alloving under air at mosphere from elemental powders, although the result is dominated by TiC. The processing route that is used in this work involves milling in air atm osphere, followed by cold compaction. The last stage is pressureless sintering at 1000 °C in vacuum furnace. Improved milling parameter should be applied in order to have better purity of Ti₃SiC₂. Milling atmosphere is probably the most important parameter that should be improved. Sintering temperature can be varie d in order to improve the result after sintering. However, it should be notice that higher sintering temperature may lead to decomposition of Ti₃SiC₂ then promoting the formation of TiC (Li, S.-B.ZhaiZhou, 2005, Li, J.-F., 2003).

Conclusions

 Ti_3SiC_2 has been successfully produced from elemental powders by a processing route that involves high energy ball milling in air atmosphere, and pressureless sintering at 1000°C. The purit y of as-milled Ti₃SiC₂ fabricated in this w ork was low. The as-milled Ti₃SiC₂ was dominated by TiC phases, with low amount of titanium silicides TiSi₂ and Ti₅Si₃. Air atmosphere, particularly o xygen played a significant role in determining the result of the as-milled powder by increasing the decreas e rate of particle size and introducing contamination to the powder during milling which may disrupt f urther mechanism. The am ount of Ti₃SiC₂ in as-sintered product was improved after pressureless sintering at 1000 °C. However, the main phase was still T iC.

Sintering process i mproved the result by inducing crystallization to amorphous phases, crystal growth to nanocrystalline phases and promoting nucleation of Ti_3SiC_2 .

References

Li J. F., Sato F.& Watanabe R., Synthesis of Ti₃SiC₂ polycrystals by hot-isostatic pressing of the elemental powders, Journal of Materials Science Letters Vol. 18, 1595-1597, (1999).

Barsoum M. W.& El-Raghy T., The MAX phases: Unique new carbide and nitride m aterials, American Scientist, Vol. 89, 334-343, (2001).

Barsoum M. W.& El-Raghy T., Synthesis and characterization of a remarkable cer amic: Ti_3SiC_2 , Journal of the A merican Ceramic Society, Vol. 79, 1953-1956, (1996).

Li H., Peng L. M., Gong M., Zhao J. H., He L. H. & Guo C. Y ., Preparation and characterization of Ti₃SiC₂ powder, Ceramics International, V ol. 30, 2289-2294, (2004).

Yeh C. L.& Shen Y . G., Effects of T iC addition on formation of T i_3SiC_2 by self-propagating high-temperature synthesis, Journal of Alloys and Compounds, Vol. 458, 286-291, (2008).

Zhou W., MEI B., ZHU J.& HONG X., S ynthesis of high-purity Ti_3SiC_2 and T i_3AlC_2 by spark plasma sintering (SPS) technique, Journal of Materi als Science Letters, Vol. 40, 2099-2100, (2005).

Zhu J., MEI B., LIU J.& XU X., Synthesis of high-purity Ti_3SiC_2 and Ti_3AlC_2 by hot-pressing (HP), Journal of Materials Science Letters, V ol. 22, 1111-1112, (2003).

Jin S., Liang B., Li J.- F.& Ren L., Effect of Al addition on phase purity of $Ti_3Si(Al)C_2$ synthesized by mechanical alloying, Journal of Materials Processing Technology, Vol. 182, 445-449, (2007).

Li S.-B.& Zhai H.-X., Sy nthesis and Reaction Mechanism of Ti_3SiC_2 by Mechanical Alloy ing of Elemental Ti, Si, and C Powders, Journal of the American Ceramic Society, Vol. 88, 2092-2098, (2005). Liang B. Y., M.Z.Wang, Sun J. F., Li X. P., Zhao Y. C.& Han X., S ynthesis of T i_3SiC_2 in air using mechanically activated 3Ti/Si/2C powder, Journal of Alloys and Compounds, Vol. 474, L18-L21, (2009). Takacs L., Self-sustaining reactions induced by ball milling, Progress in Materials Scien ce, Vol. 47, 355-414, (2002).

Li S.-B., Zhai H.-X., Zhou Y.& Zhang Z.-L., Synthesis of Ti_3SiC_2 powders by m echanically activated sintering of elemental powders of Ti, Si and C, Materials Science and Engineering A, Vol. 407, 315-321, (2005).

Jia H., Zhang Z., Qi Z., Li u G.& Bian X., Formation of nanocrystalline TiC from titanium and different carbon sources by mechanical alloying, Journal of Alloys and Compounds, Vol. 472, 97-103, (2009).

Liang B., Han X., Zou Q., Zhao Y .& Wang M., TiC/Ti₃SiC₂ composite prepared by mechanical alloying, Int. Journal of Refractory Metals & Hard Materials, Vol. 27, 664-666, (2009).

Saji S., Y asuda H.& Y amane T., Effects of the atmosphere on mechanical alloying process of Al-25at.%Ti mixed powd er, Materials Science an d Engineering A, Vol. A179/A180, 676-680, (1994). Suryanarayana C., Mechanical Alloying and Milling, ed., Marcell Dekker, (2004).

Li J.-F., Matsuki T.& Watanabe R., Mechanical-alloying-assisted synthesis of T i_3SiC_2 powder, Journal of the A merican Ceramic Society, Vol. 85, 1004-1006, (2002).

Pei Q. X., Lu C.& Lee H. P ., Crystallization of amorphous alloy during isothermal annealing: a molecular dynamics study, Journal of Ph ysics Condensed Matter, Vol. 17, 1493-1504, (2005).

Li J.-F., Matsuki T.& Watanabe R., Fabrication of highly dense Ti_3SiC_2 ceramics by pressureles s sintering of mechanically alloyed elemental powders, Journal of Materials Science, Vol. 38, 266 1-2666, (2003).